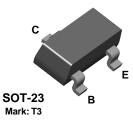
BSS63



BSS63



PNP General Purpose Amplifier

This device is designed for general purpose amplifier and switch applications requiring high voltages. Sourced from Process 74.

Absolute Maximum Ratings* TA = 25°C unless otherwise noted

Symbol	Parameter	Value	Units
V _{CEO}	Collector-Emitter Voltage	100	V
V _{CBO}	Collector-Base Voltage	110	V
V _{EBO}	Emitter-Base Voltage	6.0	V
Ic	Collector Current - Continuous	200	mA
T _J , T _{stg}	Operating and Storage Junction Temperature Range	-55 to +150	°C

*These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

NOTES:

1) These ratings are based on a maximum junction temperature of 150 degrees C.
2) These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.
3) All voltages (V) and currents (A) are negative polarity for PNP transistors.

Thermal Characteristics TA = 25°C unless otherwise noted

Symbol	Characteristic	Max	Units
		*BSS63	
P _D	Total Device Dissipation	350	mW
	Derate above 25°C	2.8	mW/∘C
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	357	°C/W

*Device mounted on FR-4 PCB 40 mm X 40 mm X 1.5 mm.

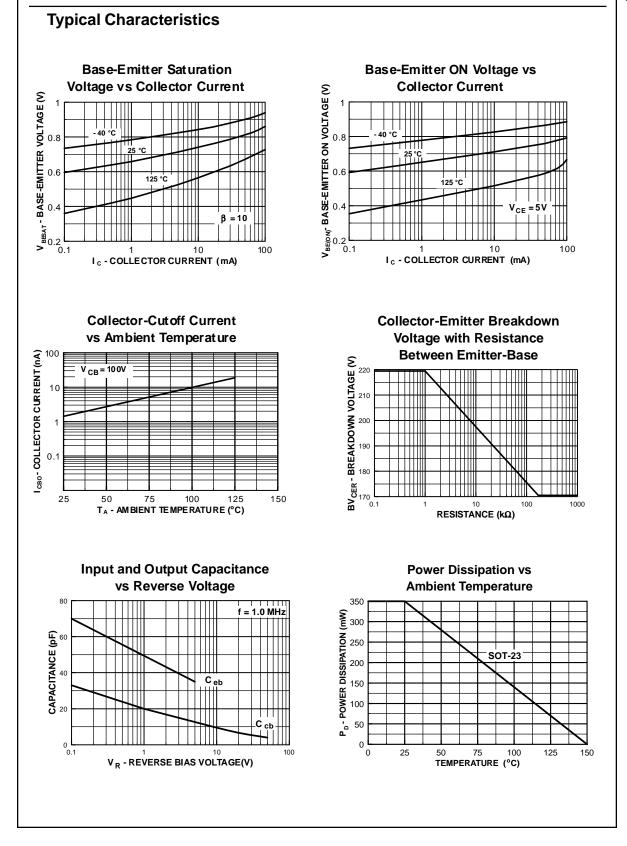
PNP General Purpose Amplifier (continued)

Symbol	Parameter	Test Conditions	Min	Max	Units
OFF CHAP	RACTERISTICS				
/ _{(BR)CEO}	Collector-Emitter Breakdown Voltage	$I_{\rm C} = 100 \ \mu {\rm A}, \ I_{\rm B} = 0$	100		V
/ _{(BR)CBO}	Collector-Base Breakdown Voltage	$I_{\rm C} = 10 \ \mu {\rm A}, \ I_{\rm E} = 0$	110		v
/ _{(BR)EBO}	Emitter-Base Breakdown Voltage	$I_{\rm E} = 1.0 \mu$ A, $I_{\rm C} = 0$	6.0		v
CBO	Collector-Cutoff Current	$V_{CB} = 90 \text{ V}, I_E = 0$	0.0	100	nA
СВО				50	μA
EBO	Emitter-Cutoff Current			200	nA
ON CHAR	ACTERISTICS				
D _{FE}	DC Current Gain	$I_{C} = 10 \text{ mA}, V_{CE} = 1.0 \text{ V}$	30		
		$I_{C} = 25 \text{ mA}, V_{CE} = 1.0 \text{ V}$	30		
V _{CE(sat)}	Collector-Emitter Saturation Voltage	$I_{\rm C} = 25$ mA, $I_{\rm B} = 2.5$ mA		0.25	V
V _{BE(sat)}	Base-Emitter Saturation Voltage	$I_{\rm C} = 25 \text{ mA}, I_{\rm B} = 2.5 \text{ mA}$		0.9	V
	GNAL CHARACTERISTICS	I _C = 25 mA, V _{CE} = 5.0,	50		MHz
T	Current Gain - Bandwidth Product		00		
NOTE: All volta	iges (V) and currents (A) are negative polarity for PNP t	f = 35 MHz transistors. 1 Ne=1.375 Ise=21.48f Ikf=.1848	Xtb=1.5 Br		
NOTE: All volta Spice PNP (Is=2 Ikr=0 Rc= Vtf=0 Xtfs Typica	Iges (V) and currents (A) are negative polarity for PNP f Model 21.48f Xti=3 Eg=1.11 Vaf=100 Bf=132. 21.6 Cjc=17.63p Mjc=.5312 Vjc=.75 Fo =0 Rb=10) I Characteristics	f = 35 MHz transistors. 1 Ne=1.375 Ise=21.48f Ikf=.1848 c=.5 Cje=73.39p Mje=.3777 Vje=.	Xtb=1.5 Br 75 Tr=1.47	'6n Tf=641	.9p ltf=0
NOTE: All volta Spice PNP (Is=2 Ikr=0 Rc= Vtf=0 Xtf= Typica	Iges (V) and currents (A) are negative polarity for PNP f Model 21.48f Xti=3 Eg=1.11 Vaf=100 Bf=132. 1.6 Cjc=17.63p Mjc=.5312 Vjc=.75 Fo =0 Rb=10) I Characteristics Typical Pulsed Current Gain	f = 35 MHz transistors. 1 Ne=1.375 Ise=21.48f Ikf=.1848 c=.5 Cje=73.39p Mje=.3777 Vje=. Collector-	Xtb=1.5 Br 75 Tr=1.47 Emitter S	ion Tf=641	.9p ltf=0
NOTE: All volta Spice PNP (Is=2 Ikr=0 Rc= Vtf=0 Xtfs Typica	Iges (V) and currents (A) are negative polarity for PNP f Model 21.48f Xti=3 Eg=1.11 Vaf=100 Bf=132. 21.6 Cjc=17.63p Mjc=.5312 Vjc=.75 Fo =0 Rb=10) I Characteristics	f = 35 MHz transistors. 1 Ne=1.375 Ise=21.48f Ikf=.1848 c=.5 Cje=73.39p Mje=.3777 Vje=.	Xtb=1.5 Br 75 Tr=1.47 Emitter S	ion Tf=641	.9p ltf=0

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PNP General Purpose Amplifier (continued)



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